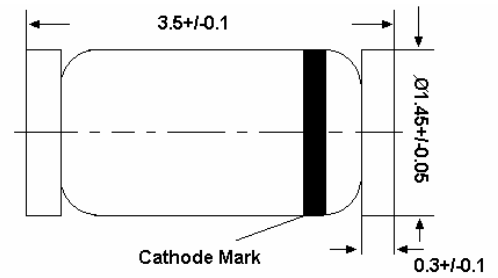


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Ultra High-Speed Switching, Voltage Clamping
Protection Circuits and Blocking Applications

Features

- Low forward voltage.
- Guard ring protected.
- Hermetically-sealed leaded glass package.
- High breakdown voltage.

LL34



Glass case MiniMELF
Dimensions in mm

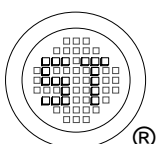
Absolute Maximum Ratings (T_a = 25°C)

Parameter	Symbol	Limits	Unit
Continuous reverse voltage	V _R	50	V
Continuous forward current	I _F	200	mA
Average forward current	I _{F(AV)}	200	mA
Repetitive peak forward current t _p ≤ 1sec.; δ ≤ 0.5	I _{FRM}	500	mA
Non-repetitive peak forward current t _p = 10ms	I _{FSM}	5	A
Operating ambient temperature	T _{amb}	-65 to +125	°C
Junction temperature	T _j	125	°C
Storage temperature range	T _S	-65 to +150	°C
Thermal resistance from junction to ambient	R _{thj-a}	320	K/W

Characteristics at T_a = 25°C

Parameter	Symbol	Min.	Typ.	Max.	Unit
Forward voltage					
at I _F = 0.1mA	V _F	-	-	300	mV
at I _F = 1mA	V _F	-	-	380	mV
at I _F = 10mA	V _F	-	-	450	mV
at I _F = 30mA	V _F	-	-	600	mV
at I _F = 100mA	V _F	-	-	900	mV
Reverse current (Note 1)					
at V _R = 40V	I _R	-	-	5	μA
Reverse recovery time					
at I _F = 10mA, I _R = 10mA, R _L = 100Ω	t _{rr}	-	-	4	ns
Diode capacitance					
at V _R = 1V, f = 1MHz	C _d	-	-	8	pF

Note 1: Pulsed test: t_p = 300μs; δ = 0.02.



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 Certificate No. 7116



ISO 9001:2000
 Certificate No. 0506098

Dated : 12/03/2005

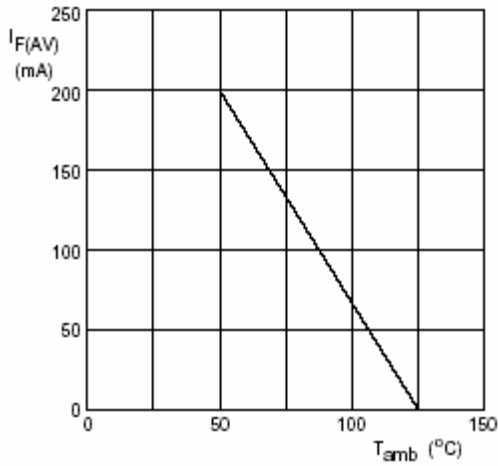
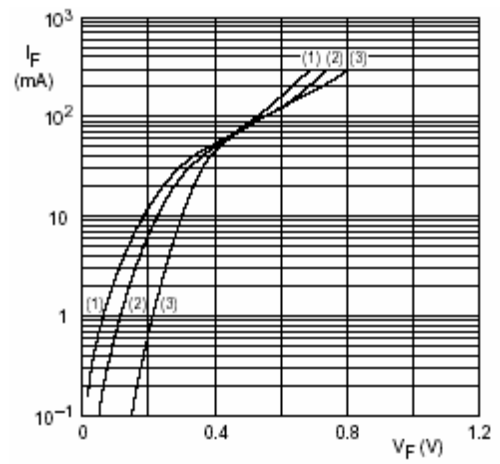
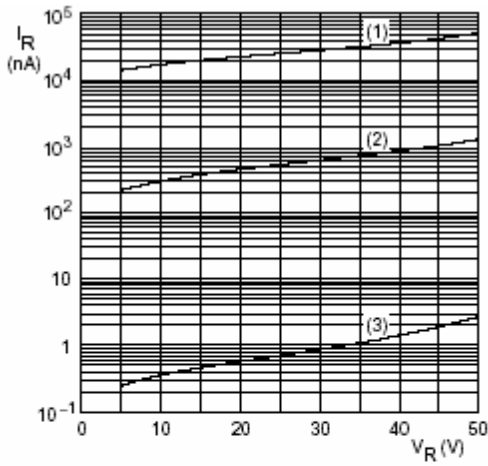


Fig. 1 Derating curve.



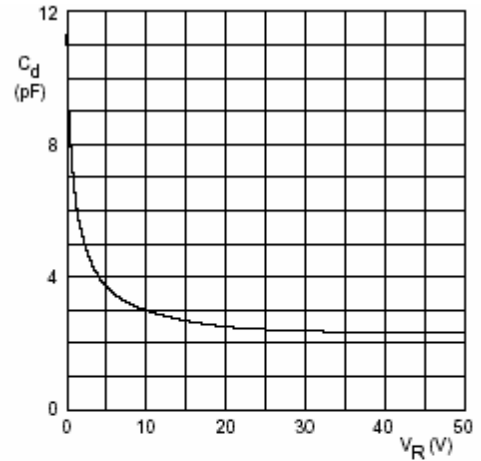
- (1) $T_{amb} = 125^\circ\text{C}$.
- (2) $T_{amb} = 85^\circ\text{C}$.
- (3) $T_{amb} = 25^\circ\text{C}$.

Fig. 2 Forward current as a function of forward voltage; typical values.



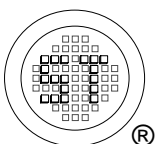
- (1) $T_{amb} = 85^\circ\text{C}$.
- (2) $T_{amb} = 25^\circ\text{C}$.
- (3) $T_{amb} = -40^\circ\text{C}$.

Fig. 3 Reverse current as a function of reverse voltage; typical values.



$f = 1\text{ MHz}$.

Fig. 4 Diode capacitance as a function of reverse voltage; typical values.



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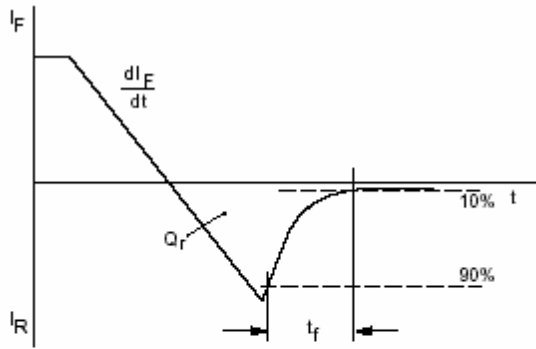
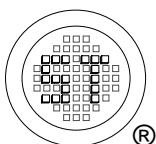


Fig. 5 Reverse recovery definitions.



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